

# HFDT Summary

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## 2 General

HF:  $300MHz - 3GHz \lambda : 1m - 1mm \rightarrow$  distributed circuits  
 $\lambda = \frac{c}{f} = \frac{c_0}{\sqrt{\epsilon_r} f}$

### 2.1 Skin effect

$$\delta_s = \frac{1}{\sqrt{\pi f \mu_0 \mu_r \sigma}}, \sigma = \text{conductivity} = \frac{1}{\rho}$$

Cylindrical conductor:  $R_{DC} = \frac{l}{\pi r^2 \sigma}, R_{AC} = \frac{l}{2\pi r \delta_s \sigma}$   
 $\frac{R_{AC}}{R_{DC}} = \frac{r}{2\delta_s}$

### 2.2 Ohm's Law

What	Symbol
Resistance	$R$
Reactance	$X$
Impedance	$Z = R + j \cdot X$
Conductance	$G = \frac{R e(Z)}{R e(Z)^2 + I m(Z)^2}$
Susceptance	$B = \frac{-I m(Z)}{R e(Z)^2 + I m(Z)^2}$
Admittance	$Y = \frac{1}{Z} = G + j \cdot B$
Imp.[Z]	Adm.[Y]
Res	$R$
Cap	$j \cdot \omega \cdot C$
In	$j \cdot \omega \cdot L$
Differential	
	$U = R \cdot I$
	$i(t) = C \cdot \frac{du(t)}{dt}$
	$u(t) = L \cdot \frac{di(t)}{dt}$
Energy	
	$\frac{1}{2} C U^2$
	$\frac{1}{2} L I^2$

### 2.3 Decibels & Neper

$$P_0(dB) = 10 \cdot \log(\frac{P}{P_0}) = 20 \cdot \log(\frac{V}{V_0})$$

$dB \rightarrow P_0 = 1W, dBm \rightarrow P_0 = 1mW$  Neper:  $\frac{P}{P_0}(Np) = \frac{1}{2} \cdot \ln(\frac{P}{P_0})$   
 $1Np = 10 \log e^2 = 8.686dB$

### 2.4 Power

Only real power is dissipated  $p(t) = u(t) \cdot i(t)$   
 $P_{peak} = Re(VI^*) = VI^* \cos(\theta)$   
 $P_{avg} = \frac{1}{2} Re(VI^*) = \frac{1}{2} VI^* \cos(\theta)$   
 Maximum Power Transfer:  $Z_{load} = Z_{generator}^*$

### 2.5 Loss in AC circuits

$$\text{Insertion Loss: } IL = 10 \log(\frac{P_{L1}}{P_{L2}}) \text{ dB}$$

$$= \frac{\text{Power-without-2-port}}{\text{Power-with-2-port}} \text{ dB}$$

$$\text{Transducer Loss TL} = 10 \log(\frac{P_A}{P_{L2}}) \text{ dB}$$

$$= \frac{\text{Max.-Power-available}}{\text{Power-with-2-port}} \text{ dB}$$

Series:  $TL = |1 + \frac{Z}{2Z_0}|^2$  Parallel:  $TL = |1 + \frac{Y}{2Y_0}|^2$

## 2.6 Resonators

Resonance Frequency: Admittance equal zero.  
 A circuit with several L and C has several resonance freq. normal:  $\omega_0 = \frac{1}{\sqrt{LC}}$

### 2.7 Quality Factor

$$Q = \frac{\text{average energy stored}}{\text{average energy dissipated}} = \frac{X}{R}$$

Q- Unloaded, External and Loaded

$$Q_U = \frac{\omega_0 L}{R_L + R_C} = \frac{1}{\omega_0 C (R_L + R_C)}$$

$$Q_E = \frac{\omega_0 L}{2Z_0} = \frac{1}{\omega_0 C (2Z_0)}$$

$$Q_L = \frac{\omega_0 L}{R_L + R_C + 2Z_0}$$

$$\frac{1}{Q_L} = \frac{1}{Q_U} + \frac{1}{Q_E}$$

#### 2.7.1 Parallel Resonator

$$Q = \frac{1}{\omega_0 LG} = \frac{\omega_0 C}{G}$$
 same as serial, replace  $R = \frac{1}{G}, B = \frac{1}{X}$

#### 2.7.2 Bandwidth

$$Q = \frac{f_0}{\Delta f} = \frac{\omega_0}{\Delta \omega}; B = \frac{1}{Q} \text{ for high Q only } (B \cdot Q = 1)!$$

higher Q means narrower Bandwidth!

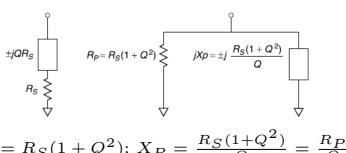
#### 2.7.3 Fano's Limit

Matching narrowband, only works for the designed frequency. Fano's limit calculates the minimum obtainable  $\Gamma_{MIN}$  over the selected bandwidth:

$$\omega_0 = \sqrt{\omega_1 \omega_2}, f_0 = \frac{\omega_0}{2\pi}, \Delta f = \frac{\omega_2 - \omega_1}{2\pi}$$

$$\Gamma_{MIN} \geq e^{-(\frac{\pi}{Q})(\frac{f_0}{\Delta f})}$$

### 2.8 Series to parallel equivalent circuit



$$Z = R_S + jX = R_S(1 + jQ)$$

$$Y = \frac{1 - jQ}{R_S(1 + Q^2) = G - jB}$$

## 3 Q-Matching

To increase bandwidth use multiple stages with lower Q use n sections:  $1 + Q^2 = \sqrt[n]{R}$   $\rightarrow$  do the transformation n times

### 3.1 Low to high Resistance

$R_P = \text{target Resistance}; R_S = R_L$

$$1. \text{ Find target Q } (R_P = R_S(1 + Q^2)); Q = \sqrt{\frac{R_P}{R_S} - 1}$$

2. Add L or C ( $X_{LC}$ ) in series ( $X_S$  is the target reactance and we want to achieve it with the help of the series reactance)

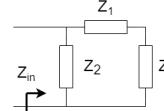
$$\rightarrow X_{LC} + X_L = \pm X_S = \pm Q \cdot R_S$$

If  $X_S = \pm X_L$  no L or C element has to be added.

3. Convert to parallel ( $X_P = \frac{R_S(1+Q^2)}{Q}$ , keep sign)

4. Add C or L in parallel to cancel out (resonate) the reactive part ( $X_P$ )

5. Check input impedance!



### 3.2 High to low Resistance

$$Q_L = \frac{X_L}{R_L}; R_S = \text{target Resistance}$$

1. Convert to parallel representation

$$R_{PL} = R_L(1 + Q_L^2); X_{PL} = \frac{R_L(1 + Q_L^2)}{Q_L} \text{ Sign of imag. part stays the same!}$$

$$2. \text{ Find target Q: } Q = \sqrt{\frac{R_{PL}}{R_S} - 1}$$

3. Add L or C ( $X_{LC}$ ) in parallel,  $X_P$  has sign of  $X_{PL}$

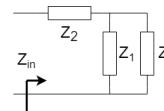
$$X_P = \frac{R_{PL}}{Q} \rightarrow X_P = \frac{X_{PL} X_{LC}}{X_{PL} + X_{LC}}$$

$$\rightarrow X_{LC} = \frac{X_P X_{PL}}{X_{PL} - X_P}$$

4. Convert to series representation  $X_S = Q \cdot R_S$  (keep the sign)

5. Add L or C in series to cancel out (resonate) the reactive part ( $X_S$ )

6. Check input impedance!

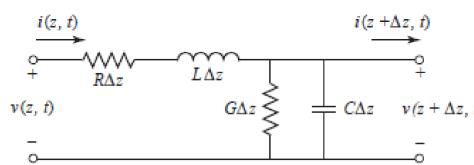


## 4 Transmission Line

• Device/circuit dimensions are in the same order as  $\lambda$  ( $l > \frac{\lambda}{10}$ )

• Lumped Elements are not used at HF because of parasitic behaviour

• One piece of transmission line with length  $\Delta z$  can be modeled as a lumped element circuit  $\rightarrow$  TL = periodic circuit of infinitely many of those elements



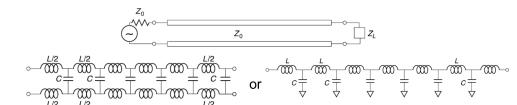
Characteristics:

1. Uniform Crosssection

2. Separation between the two conductors  $<< \lambda$

3. Characteristic Impedance  $Z_0$  (= voltage to current ratio traveling in a direction)

4. distributed behaviour



### 4.1 Telegraphers equations & some formulas

Voltage and Current are not constant, it is a superposition of a forward  $\rightarrow$  and reflected  $\leftarrow$  wave. We get a standing wave pattern. For  $\Delta z \rightarrow 0$ :  $\frac{\delta V}{\delta z} = -(R + j\omega L) \cdot I$ ;  $\frac{\delta I}{\delta z} = -(G + j\omega C) \cdot V$

Current:  $I = I_I e^{-\gamma z} - I_R e^{\gamma z} \rightarrow + \leftarrow$

Voltage:  $V = V_I e^{-\gamma z} + V_R e^{\gamma z} \rightarrow + \leftarrow$

propagation const:  $\gamma = \sqrt{(R + j\omega L)(G + j\omega C)} = \alpha + j\beta$

Phase constant:  $\beta = \frac{rad}{m}; \lambda = \frac{2\pi}{\beta}; \beta z = \omega t$

attenuation constant:  $\alpha = \frac{Np}{m}$  low loss  $\rightarrow \alpha \approx \frac{R}{2Z_0}$

The attenuation const.  $\alpha$  defines the loss of the TL often given in dB.  $Z_0 = \frac{V_L}{I_L} = \frac{V_R}{I_R} = \frac{R + j\omega L}{\gamma} = \sqrt{\frac{R + j\omega L}{G + j\omega C}}$  complex!

Wavelength:  $\lambda = \frac{2\pi}{\beta}$

### 4.2 Lossless Line

$$\beta = \omega \sqrt{LC}, \alpha = 0, Z_0 = \sqrt{LC}$$

Incident + Reflected wave:

Current:  $I = I_I e^{-j\beta z} - I_R e^{j\beta z} = I_I e^{-j\beta z} [1 - \Gamma L e^{2j\beta z}]$

Voltage:  $V = V_I e^{-j\beta z} + V_R e^{j\beta z} = V_I e^{-j\beta z} [1 + \Gamma L e^{2j\beta z}]$

Phase caused by a TL:  $\theta = \beta l = \frac{2\pi}{\lambda} l = \frac{\omega l}{v_p}$

if lossy, replace  $\beta$  with  $\gamma$

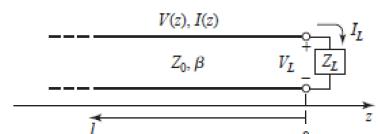
### 4.3 Phase & Group Velocities

phase velocity:  $v_p = \frac{\omega}{\beta} = \lambda f = \frac{c_0}{\sqrt{\epsilon_r}} = \frac{1}{\sqrt{LC}}$

$$e^{j(\omega t - \beta z)} = e^{j\omega(t - z/v_p)}$$

$$\text{group velocity: } v_G = \frac{d\omega}{d\beta} = \frac{1}{1 - (\frac{\omega}{v_p})(\frac{dv_p}{d\omega})}$$

### 4.4 Reflection Coefficient



$$\Gamma = |\Gamma| \angle \phi = |\Gamma| e^{j\phi}$$

Derivation at  $z=0$  (load):

$$V(0) = V_I(0) + V_R(0) = I(0) \cdot Z_L$$

$$I(0) = I_I(0) - I_R(0) = \frac{1}{Z_0} (V_I(0) - V_R(0))$$

$$V_I(0) + V_R(0) = \frac{1}{Z_0} (V_I(0) - V_R(0)) \cdot Z_L$$

$$\Rightarrow V_R(0) = \frac{Z_L - Z_0}{Z_L + Z_0} V_I(0)$$

$$\Gamma(z) = \frac{V_R(z)}{V_I(z)} = \frac{I_R(z)}{I_I(z)} = \Gamma(0) e^{2j\beta z} \text{ (lossless)}$$

$$\Gamma_L = \frac{Z_L - Z_0}{Z_L + Z_0}$$

$$\Gamma_{in} = \frac{Z_{in} - Z_0}{Z_{in} + Z_0} = \Gamma_L e^{-2\gamma l} == \Gamma_L e^{-2l(\alpha + j\beta)}$$

No reflection  $\rightarrow \Gamma = 0$

$$V(z) = V_I(z)(1 + \Gamma(z))$$

$$I(z) = I_I(z)(1 - \Gamma(z))$$

$$P_{avg} = \frac{1}{2} \frac{|V_{I0}|^2}{Z_0} (1 - |\Gamma(0)|^2)$$

Return Loss  $RL = -10 \log(|\Gamma|^2)$  dB,  $|\Gamma| = 10^{-\frac{RL}{20}}$

(the fraction of power reflected from the load)

Mismatch loss  $= -10 \log(1 - |\Gamma|^2)$  dB

(the fraction of power absorbed at the load)

## 4.5 Voltage Standing Wave Ratio (VSWR)

Max. Voltage of standing wave:  $V_{max} = |V_I|(1 + |\Gamma|)$

Min. Voltage of standing wave:  $V_{min} = |V_I|(1 - |\Gamma|)$

$$VSWR = \frac{V_{max}}{V_{min}} = \frac{1+|\Gamma|}{1-|\Gamma|}$$

$$\Gamma = \frac{VSWR-1}{VSWR+1} = 10^{-\frac{RL(dB)}{20}}$$

- Distance between maxima (minima) is  $\frac{\lambda}{2}$

- Distance between maxima and minima is  $\frac{\lambda}{4}$

Just for lossless:

- Because voltage and current on the line aren't constant, impedance looking into the transmission line will vary with position  $x$ :  $Z(x) = \frac{V(x)}{I(x)} = Z_0 \frac{1+\Gamma(x)}{1-\Gamma(x)}$

- Since  $\Gamma(x) = \frac{Z(x)-Z_0}{Z(x)+Z_0}$  and  $\Gamma_L = \frac{Z_L-Z_0}{Z_L+Z_0}$  we get  $Z(x) = Z_0 \frac{Z_L+jZ_0\tan\beta x}{Z_0+jZ_L\tan\beta x}$

## 4.6 Input Impedance

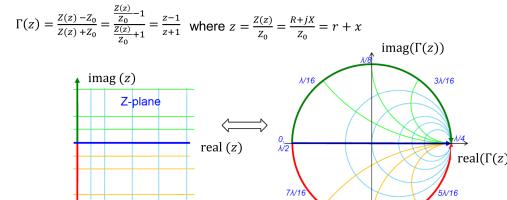
- At input  $z = -1$  we get:  $Z_{in} = Z_0 \frac{Z_L+jZ_0\tan\theta}{Z_0+jZ_L\tan\theta}$

- with loss:  $Z_{in} = Z_0 \frac{Z_L+jZ_0\tanh\gamma l}{Z_0+jZ_L\tanh\gamma l}$

Special Cases (lossless):

- impedance matched:  $Z_L = Z_0 \rightarrow Z_{in} = Z_0$
- lambda half:  $l = n \frac{\lambda}{2} \rightarrow Z_{in} = Z_L$
- lambda quarter:  $l = \frac{\lambda}{4} \rightarrow Z_{in} = \frac{Z_L^2}{Z_L}$
- shorted TL:  $Z_{in} = jZ_0\tan\theta \rightarrow$  inductive for  $\theta < 90^\circ$ , capacitive for  $90^\circ < \theta < 180^\circ$
- open TL:  $Z_{in} = -jZ_0\tan\theta \rightarrow$  capacitive for  $\theta < 90^\circ$ , inductive for  $90^\circ < \theta < 180^\circ$

## 5 Smith Chart



Addmitance Smith chart:  $\Gamma = \frac{1-y}{1+y}$

- At a fixed frequency, movement from the load toward the generator results in a clockwise rotation on the Smith Chart.

- As frequency increases, reflection coefficients always rotate clockwise

### 5.1 Matching

- There are two types:

1. impedance matching (no reflection)
2. complex conjugate matching (max power is delivered to the load)

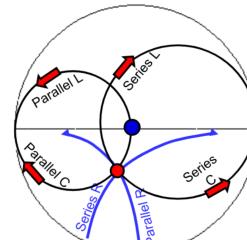
- Matching can be done with:

- Lumped LC elements
- Sections of Transmission line (stub with open or short circuit, series TL)
- Mix of both

- Matching narrowband, only works for the designed frequency. Fano's limit calculates the minimum obtainable  $\Gamma_{MIN}$  over the selected bandwidth:

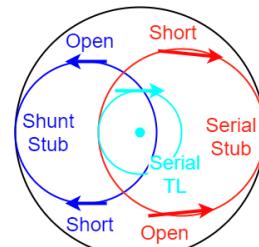
$$\Gamma_{MIN} \geq e^{-(\frac{\pi}{Q})(\frac{f_0}{\Delta f})}$$

### 5.2 LC Matching



High to Low: first Parallel (stub) then Serial  
Low to High: first Serial then Parallel (stub)

### 5.3 Transmission Line (TL) Matching



#### 5.3.1 Serial TL

- Making TL to the load longer  $\rightarrow$  rotate around center point in clockwise direction on const.  $\Gamma$  (radius)  $\rightarrow$  lossless.
- If Loss is respected the line spirals towards center (matched point) of the smith chart.
- $Z_0 = \sqrt{Z_{max}Z_{min}}$

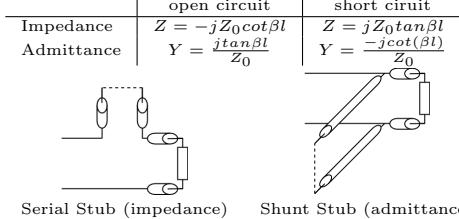
Match any complex load to any complex generator:

We want:  $Z_{in} = R_G - jX_G \stackrel{!}{=} Z_0 \frac{Z_L+jZ_0\tan\theta}{Z_0+jZ_L\tan\theta} \rightarrow$  solve for complex  $Z_0$ ; often  $\theta = \beta l$  (lossless)

#### 5.3.2 Stub TL

theoretically both (open or short) can be used as cap/induc. but the TL would have to be  $> \pi/2$  and therefore it takes more area

$$\beta = \frac{2\pi}{\lambda}$$



### 5.4 Quarter wave transformer

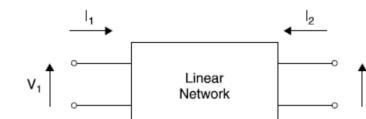
TL with a length of  $\frac{\lambda}{4}$  and a characteristic impedance which has to be defined.

$$\text{derivation: } Z_{in} = Z_0 \frac{Z_L+jZ_0\tan\beta l}{Z_0+jZ_L\tan\beta l} = Z_0 \frac{Z_0}{Z_L} \text{ for } l = \frac{\lambda}{4}$$

$$\rightarrow Z_{in} = \frac{Z_0^2}{Z_L} \Rightarrow Z_0 = \sqrt{Z_{in}Z_L}$$

to make the transformation more wideband by doing the transformation in  $n \frac{\lambda}{4}$  steps, each providing a  $\sqrt[n]{\frac{Z_L}{Z_{in}}}$  transformation.

## 6 Matrix Network Analysis



$$V_1 = Z_{11}I_1 + Z_{12}I_2$$

$$V_2 = Z_{21}I_1 + Z_{22}I_2$$

$$\text{Impedance: } \begin{pmatrix} V_1 \\ V_2 \end{pmatrix} = \begin{pmatrix} Z_{11} & Z_{12} \\ Z_{21} & Z_{22} \end{pmatrix} \begin{pmatrix} I_1 \\ I_2 \end{pmatrix}$$

$$Z_{11} = \frac{V_1}{I_1} \Big|_{I_2=0}$$

$$Z_{21} = \frac{V_2}{I_1} \Big|_{I_2=0}$$

$$\text{Admittance: } \begin{pmatrix} I_1 \\ I_2 \end{pmatrix} = \begin{pmatrix} Y_{11} & Y_{12} \\ Y_{21} & Y_{22} \end{pmatrix} \begin{pmatrix} V_1 \\ V_2 \end{pmatrix}$$

$$Y_{11} = \frac{I_1}{V_1} \Big|_{V_2=0}$$

$$Y_{21} = \frac{I_2}{V_1} \Big|_{V_2=0}$$

$$Y_{12} = \frac{I_1}{V_2} \Big|_{V_1=0}$$

$$Y_{22} = \frac{I_2}{V_2} \Big|_{V_1=0}$$

## 6.2 Special Networks

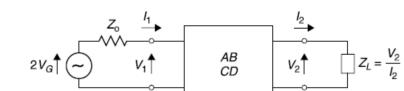
### 6.2.1 Reciprocal Network

Its elements are bilateral and linear (not containing any active devices, ferrites, plasma...)  $Z_{12} = Z_{21}$ ;  $Y_{12} = Y_{21}$

### 6.2.2 Symmetric Network

$$Z_{11} = Z_{22}; Z_{12} = Z_{21}$$

### 6.3 ABCD (transmission) Matrix



$$A = \frac{V_1}{V_2} \Big|_{I_2=0} \quad B = \frac{V_1}{I_2} \Big|_{V_2=0}$$

$$C = \frac{I_1}{V_2} \Big|_{I_2=0} \quad D = \frac{I_1}{I_2} \Big|_{V_2=0}$$

ABCD matrix of the cascade connection of several two port network can be found just by multiplying the ABCD matrices of individual two ports:

$$\begin{pmatrix} A_T & B_T \\ C_T & D_T \end{pmatrix} = \begin{pmatrix} A_1 & B_1 \\ C_1 & D_1 \end{pmatrix} \cdot \begin{pmatrix} A_2 & B_2 \\ C_2 & D_2 \end{pmatrix} = \begin{pmatrix} (A_1A_2 + B_1C_2) & (A_1B_2 + B_1D_2) \\ (C_1A_2 + D_1C_2) & (C_1B_2 + D_1D_2) \end{pmatrix}$$

$$\text{Reciprocal: } AD - BC = 1$$

$$\text{Symmetrical: } A = D$$

$$\text{Lossless: } |S_{11}|^2 + |S_{21}|^2 = 1 \text{ and } |S_{21}|^2 + |S_{22}|^2 = 1$$

Circuit	ABCD Parameters
$Z$	$A = 1 \quad B = Z \quad C = 0 \quad D = 1$
$\Gamma$	$A = 1 \quad C = \Gamma \quad B = 0 \quad D = 1$
$Z_0, \beta$	$A = \cos\beta l \quad C = jZ_0 \sin\beta l \quad B = Z_0 \sin\beta l \quad D = \cos\beta l$
$N:1$	$A = N \quad C = 0 \quad B = 0 \quad D = \frac{1}{N}$
$T_1, T_2$	$A = 1 + \frac{Y_1}{Y_2} \quad C = Y_1 + Y_2 + \frac{Y_1 Y_2}{Y_3} \quad B = \frac{1}{Y_2} \quad D = 1 + \frac{Y_1}{Y_3}$
$Z_1, Z_2, Z_3$	$A = 1 + \frac{Z_1}{Z_3} \quad C = \frac{1}{Z_3} \quad B = Z_1 + Z_2 + \frac{Z_1 Z_2}{Z_3} \quad D = 1 + \frac{Z_2}{Z_3}$

Input Impedance:

$$V_1 = AV_2 + BI_2; I_1 = CV_2 + DI_2$$

$$Z_{in} = \frac{AV_2 + BI_2}{CV_2 + DI_2} = \frac{A(V_2/I_2) + B}{C(V_2/I_2) + D} = \frac{AZ_L + B}{CZ_L + D}$$

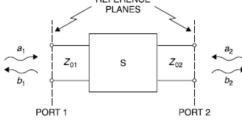
Insertion Loss:  $IL = \frac{1}{4}|A + \frac{B}{Z_0} + CZ_0 + D|^2$  ( $Z_L = Z_0 = real$ )

## 6.4 Scattering Matrix (S-Parameters)

$S_{ii}$  is the reflection coefficient seen looking into port i when all other ports are terminated in matched loads  
 $S_{ij}$  is the transmission coefficient from port j to port i when all other ports are matched loads  
Instead of measuring voltages and currents at the ports (for Z,Y,ABCD), S parameters are obtained by measuring intensities of the incident and reflected waves (at certain conditions: matching is achieved!)

**Reciprocal:**  $[S] = [S]^T \rightarrow$  symmetric

**Lossless:**  $|S_{11}|^2 + |S_{21}|^2 = 1$ , transmitted power:  
 $|S_{12}|^2 = |S_{21}|^2$   
dissipated power = 1 - transmitted power



$b_i$ : reflected wave,  $a_i$ : incident wave

$$\begin{pmatrix} b_1 \\ b_2 \end{pmatrix} = \begin{pmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{pmatrix} \cdot \begin{pmatrix} a_1 \\ a_2 \end{pmatrix}$$

$$a_1 = \frac{V_{I1}}{\sqrt{Z_{01}}} \quad b_1 = \frac{V_{R1}}{\sqrt{Z_{01}}}$$

$$a_2 = \frac{V_{I2}}{\sqrt{Z_{02}}} \quad b_2 = \frac{V_{R2}}{\sqrt{Z_{02}}}$$

Reflection:

$$S_{11} = \left. \frac{b_1}{a_1} \right|_{a_2=0} = \left. \frac{V_{R1}}{V_{I1}} \right|_{V_{I2}=0} = \Gamma_1 \Big|_{V_{I2}=0}$$

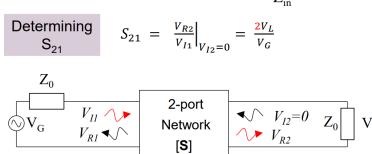
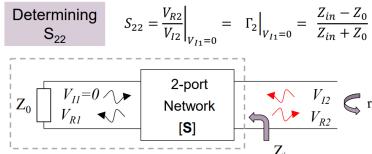
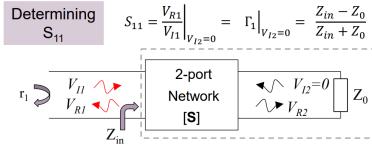
$$S_{22} = \left. \frac{b_2}{a_2} \right|_{a_1=0} = \left. \frac{V_{R2}}{V_{I2}} \right|_{V_{I1}=0} = \Gamma_2 \Big|_{V_{I1}=0}$$

Transmission:

$$S_{21} = \left. \frac{b_2}{a_1} \right|_{a_2=0} = \left. \frac{V_{R2}}{V_{I1}} \right|_{V_{I2}=0}$$

$$S_{12} = \left. \frac{b_1}{a_2} \right|_{a_1=0} = \left. \frac{V_{R1}}{V_{I2}} \right|_{V_{I1}=0}$$

Even though Z, Y, and ABCD parameters cannot be practically measured at RF frequencies they can be obtained by conversion from the measured S parameters



$S_{12}$  is similar to  $S_{21}$

$$S_{21} = \left. \frac{b_2}{a_1} \right|_{a_2=0} = \left. \frac{V_2^2}{V_1^+} \right|_{Z_0 \text{ at port 2}}$$

often:  $V_2^- = V_2$  when the load is matched;  $V_1^+ = V_1^-$

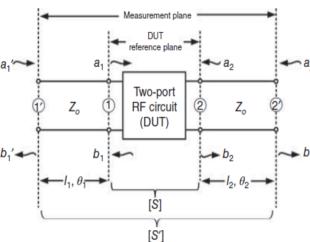
$$S_{11}V_1^+ \rightarrow \text{solve for } V_1^+$$

### 6.4.1 S parameters of a TL

$$\begin{pmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{pmatrix} = \begin{pmatrix} 0 & e^{-\gamma l} \\ e^{-\gamma l} & 0 \end{pmatrix}$$

### 6.4.2 Problems when determining S parameters

- Measurements of individual circuits, components or devices often cannot be done directly at individual ports
- As a result, the actual measurement at reference planes are different from those of the interested RF device under test (DUT)
- However, S parameters of a DUT can be obtained from the measured S parameters with a simple calculation: shifting of the reference planes



$$\begin{pmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{pmatrix} = \begin{pmatrix} S'_{11}e^{j2\theta_1} & S'_{12}e^{j(\theta_1+\theta_2)} \\ S'_{21}e^{j(\theta_1+\theta_2)} & S'_{22}e^{j2\theta_2} \end{pmatrix} \text{ When load is mismatched:}$$

$$\begin{cases} I_L = \frac{a_2}{b_2} = \frac{V_2^+}{V_2^-} = \frac{Z_L - Z_0}{Z_L + Z_0} \\ I_S = \frac{a_1}{b_1} = \frac{V_1^+}{V_1^-} = \frac{Z_S - Z_0}{Z_S + Z_0} \end{cases} \quad \begin{cases} I_{out} = \frac{b_2}{a_2} = \frac{V_2^-}{V_2^+} = \frac{1}{I_L} \frac{Z_{out} - Z_0}{Z_{out} + Z_0} \\ I_{in} = \frac{b_1}{a_1} = \frac{V_1^-}{V_1^+} = \frac{1}{I_S} \frac{Z_{in} - Z_0}{Z_{in} + Z_0} \end{cases}$$

$$\begin{cases} V_1^- = S_{11}V_1^+ + S_{12}V_2^+ = S_{11}V_1^+ + S_{12}\Gamma_L V_2^- \\ V_2^- = S_{21}V_1^+ + S_{22}V_2^+ = S_{21}V_1^+ + S_{22}\Gamma_L V_2^- \end{cases} \quad \begin{cases} \Gamma_{in} = \frac{V_1^-}{V_1^+} = S_{11} + \frac{S_{12}S_{21}\Gamma_L}{1 - S_{22}\Gamma_L} \\ \Gamma_{out} = \frac{V_2^+}{V_2^-} = S_{22} + \frac{S_{12}S_{21}\Gamma_S}{1 - S_{11}\Gamma_S} \end{cases}$$

If  $Z_L = Z_0$  and  $Z_S = Z_0$   $\rightarrow I_L = I_S = 0$   $\rightarrow I_{out} = S_{22}$  and  $I_{in} = S_{11}$

### 6.4.3 S parameters

$$\text{TL: } \begin{pmatrix} V_R^1 \\ V_R^2 \end{pmatrix} = \begin{pmatrix} 0 & e^{-j\theta} \\ e^{-j\theta} & 0 \end{pmatrix} \begin{pmatrix} V_I^1 \\ V_I^2 \end{pmatrix}$$

## 7 Amplifier Design

### 7.1 Stability

$\Gamma_{in} = S_{11} + \frac{S_{12}S_{21}\Gamma_L}{1 - S_{22}\Gamma_L}$   $\Gamma_{out} = S_{22} + \frac{S_{12}S_{21}\Gamma_S}{1 - S_{11}\Gamma_S}$  Oscillation is possible if either the input or output port reflection coefficient has a magnitude larger than 1

### 7.1.1 Types of stability

unconditional stability:

The network is unconditionally stable if  $|\Gamma_{in}| < 1$  and  $|\Gamma_{out}| < 1$  for all passive source and load impedances ( $|\Gamma_S| < 1$  and  $|\Gamma_L| < 1$ )

conditional stability:

The network is conditionally stable if  $|\Gamma_{in}| < 1$  and  $|\Gamma_{out}| < 1$  only for a certain range of passive source and load impedances. This case is also referred to as potentially unstable

### 7.1.4 Test for unconditional Stability (K-Δ Test)

$$K = \frac{1 - |S_{11}|^2 - |S_{22}|^2 + |\Delta|^2}{2|S_{12}S_{21}|} > 1$$

$$|\Delta| = |S_{11}S_{22} - S_{12}S_{21}| < 1$$

both have to be satisfied simultaneously, if the condition is not satisfied, stability circles should be constructed for the designed frequency and input and output matching network should be designed away from the unstable regions

### 7.2 Gain

For a two-port network characterized by its S parameter matrix and source and load impedances  $Z_S$  and  $Z_L$  we can define three types of gain:

$$\bullet \text{ Voltage Gain: } A_v = \frac{S_{21}\Gamma_L + S_{21}}{1 - S_{22}\Gamma_L + S_{11}(1 - S_{22}\Gamma_L) + S_{21}\Gamma_L S_{12}}$$

$$\bullet \text{ Power gain is the ratio of power dissipated in the load to the power delivered to the input of the two-port network } G_P = \frac{P_L}{P_{in}} = \frac{|S_{21}|^2(1 - |\Gamma_L|^2)}{(1 - |\Gamma_{in}|^2)(1 - S_{22}\Gamma_L)^2}$$

$$\bullet \text{ Available power gain is the ratio of the power available from the two-port } G_A = \frac{P_{avv}}{P_{avv}} = \frac{|S_{21}|^2(1 - |\Gamma_S|^2)}{(1 - |\Gamma_{out}|^2)(1 - S_{11}\Gamma_S)^2}$$

### 7.2.1 Transducer Power Gain

$G_T$  is the ratio of the power delivered to the load to the power available from the source

$$G_T = \frac{P_L}{P_{avv}} = \frac{|S_{21}|^2(1 - |\Gamma_L|^2)(1 - |\Gamma_L|^2)}{|1 - \Gamma_{in}\Gamma_S|^2 |1 - S_{22}\Gamma_L|^2}$$

$$\bullet \text{ Input matching gain: } G_S = \frac{(1 - |\Gamma_S|^2)}{|1 - \Gamma_{in}\Gamma_S|^2}, \text{ if transistor is unilateral then } S_{12} = 0 \text{ and } G_S = \frac{(1 - |\Gamma_S|^2)}{|1 - S_{11}\Gamma_S|^2}$$

$$\bullet \text{ Transistor gain: } G_0 = |S_{21}|^2$$

$$\bullet \text{ Output matching gain: } G_L = \frac{(1 - |\Gamma_L|^2)}{|1 - S_{22}\Gamma_L|^2}$$

$$\text{For unilateral transistor: } G_{Smax} = \frac{1}{1 - |S_{11}|^2} \quad (\Gamma_S = S_{11}^*), \quad g_S = \frac{G_S}{G_{Smax}}$$

$$G_{Lmax} = \frac{1}{1 - |S_{22}|^2} \quad (\Gamma_L = S_{22}^*), \quad g_L = \frac{G_L}{G_{Lmax}}$$

$$\text{Constant input gain circle: } C_S = \frac{g_S S_{11}^*}{1 - (1 - g_S)|S_{11}|^2}, \quad R_S = \frac{\sqrt{1 - g_S}(1 - |S_{11}|^2)}{1 - (1 - g_S)|S_{11}|^2}$$

$$\text{Constant output gain circle: } C_L = \frac{g_L S_{22}^*}{1 - (1 - g_L)|S_{22}|^2}, \quad R_L = \frac{\sqrt{1 - g_L}(1 - |S_{22}|^2)}{1 - (1 - g_L)|S_{22}|^2}$$

### 7.3 Noise

$$\bullet \text{ Unbiased resistor generates a random thermal noise voltage } P_n = (\frac{V_n}{2R})^2; R = \frac{V_n^2}{4kTBR} = kTB; V_n = \sqrt{4kTBR}$$

$$\bullet \text{ The measure of signal degradation in the signal-to-noise ratio between input and output is called the noise figure: } F = \frac{S_1/N_L}{S_O/N_O}$$

$$\bullet \text{ Noise figure of the cascaded system is determined by the Friis formula: } F = F_1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1 G_2} \dots$$

- The noise figure of a two port amplifier can be expressed as:  $F = F_{min} + \frac{R_N}{G_S} |Y_S - Y_{S,opt}|$

- source admittance:  $Y_s = G_S + jB_S$
- source admittance that results in the minimum noise figure  $Y_{S,opt}$
- minimum noise figure when admittance is  $Y_{S,opt}$ :  $F_{min}$
- equivalent noise resistance:  $R_N$

- instead of  $Y_s, Y_{S,opt}$  we can use  $\Gamma_S, \Gamma_{S,opt}$ :

$$F = F_{min} + \frac{4R_N}{Z_0} \frac{|\Gamma_S - \Gamma_{S,opt}|^2}{(1-|\Gamma_S|^2)(1+\Gamma_{S,opt})^2}$$

- We can define a noise figure parameter N:

$$N = \frac{|\Gamma_S - \Gamma_{S,opt}|^2}{1-|\Gamma_S|^2} = \frac{F - F_{min}}{4R_N Z_0} |1 + \Gamma_{S,opt}|^2$$

- circle solution:

$$CF = \frac{\Gamma_{opt}}{N+1}, RF = \frac{\sqrt{N(N+1-|\Gamma_{opt}|^2)}}{N+1}$$

## 7.4 Amplifier Design Techniques

### 7.4.1 Design for specific gain and best possible noise

- Draw noise circles for several noise figures F close to  $F_{min}$
- Find the sum of the gains for the input and output matching networks
- Take into account that maximum gain you can get from the output is  $10\log \frac{1}{1-|S_{22}|^2}$
- Draw several  $G_S$  and choose which input matching intersects with the smallest noise circle
- For a fixed  $G_S$  now you can calculate  $G_L$  and then draw  $G_L$  circle
- Choose  $\Gamma_S$  and  $\Gamma_L$  where  $G_S$  and  $G_L$  circles intersect the least noise figure circle and are close as possible to center of the Smith chart

### 7.4.2 Design for specific noise and best possible gain

- $\Gamma_L = \Gamma_{out}^*$  we can maximize it because noise figure does not depend on output. If unilateral:  $\Gamma_L = S_{22}^*$
- Draw the noise circle for desired F
- Find maximum input matching circuit gain  $G_S$  for which the noise circle and input gain circle have 1 common point. That point will be the desired  $\Gamma_S$
- Amplifier gain is now:

$$G_T(dB) = 10\log|S_{21}|^2 + 10\log \frac{1-|\Gamma_S|^2}{1-|G_{in}\Gamma_S|^2} + 10\log \frac{1-|\Gamma_L|^2}{|1-S_{22}\Gamma_L|^2}$$

if unilateral:  
 $G_{TU}(dB) = 10\log|S_{21}|^2 + 10\log \frac{1-|\Gamma_S|^2}{1-S_{11}\Gamma_S|^2} + 10\log \frac{1}{1-|S_{22}|^2}$

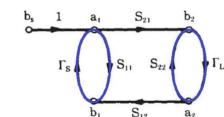
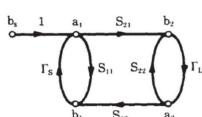
### 7.4.3 Design for minimum noise and best possible gain

- $\Gamma_L = \Gamma_{out}^*$  if unilateral:  $\Gamma_L = S_{22}^*$
- Minimum noise occurs for  $\Gamma_S = \Gamma_{S,opt}$

- Amplifier gain is now:

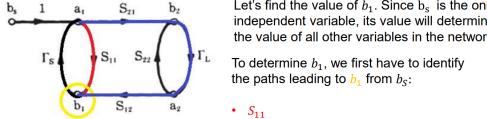
$$G_T(dB) = 10\log|S_{21}|^2 + 10\log \frac{1-|\Gamma_S|^2}{|1-\Gamma_{in}\Gamma_S|^2} + 10\log \frac{1-|\Gamma_L|^2}{|1-S_{22}\Gamma_L|^2}$$

$$\text{if unilateral: } G_{TU}(dB) = 10\log|S_{21}|^2 + 10\log \frac{1-|\Gamma_S|^2}{|1-S_{11}\Gamma_S|^2} + 10\log \frac{1}{1-|S_{22}|^2}$$



**Second Order Loop:** is defined as the product of any two non-touching first order loops. Of the three first order loops just found only  $S_{11}\Gamma_s$  and  $S_{22}\Gamma_L$  do not touch.

**Third Order Loop:** is the product of any three non-touching first order loops. (no third order loop for this example)



Let's find the value of  $b_1$ . Since  $b_3$  is the only independent variable, its value will determine the value of all other variables in the network.

To determine  $b_1$ , we first have to identify the paths leading to  $b_1$  from  $b_3$ :

- $S_{11}$
- $S_{21}\Gamma_L S_{12}$

Let's identify the non-touching loops with respect to the paths just found:

- $S_{11}$  → First order loop  $S_{22}\Gamma_L$  have no nodes or branches in common
- $S_{21}\Gamma_L S_{12}$  touches all of the network's first order loop → no non-touching loops

It is now time to use **Mason's Rule** to determine the ratio of the variables  $b_1$  and  $b_3$ .

Let's apply this rule to our case:

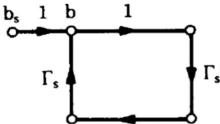
$$\frac{b_1}{b_3} = T = \frac{(S_{11}[1-S_{22}\Gamma_L] + S_{21}\Gamma_L S_{12}[1])}{1-(S_{11}\Gamma_s + S_{22}\Gamma_L + S_{21}\Gamma_L S_{12}\Gamma_s) + S_{11}\Gamma_s S_{22}\Gamma_L}$$

Although the example exploits a rather simple network, the expressions can become complicated.

Mason's Rule provides a systematic approach to determine various transfer functions (usable for far more complex systems, as the error correction model for a VNA seen during the lecture).

### Power Available from the Source

Power available from the source is the power delivered to a conjugate-matched load ( $\Gamma_L = \Gamma_s^*$ ).



$$P_{av} = |b|^2 - |a|^2$$

Applying **Mason's Rule:**

$$b = \frac{b_s}{1-\Gamma_s\Gamma_s^*}, \quad a = \frac{b_s\Gamma_s^*}{1-\Gamma_s\Gamma_s^*}$$

$$P_{av} = \frac{|b_s|^2(1-|\Gamma_s|^2)}{(1-|\Gamma_s|^2)^2} = \frac{|b_s|^2}{1-|\Gamma_s|^2}$$

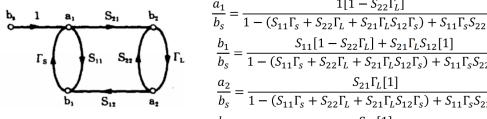
So:

### Voltage Gain

For a two-port network:

$$A_V = \frac{V_{out}}{V_{in}}$$

Recalling the total voltage on a T-line is  $V = V^+ + V^-$ :



$$A_V = \frac{a_2 + b_2}{a_1 + b_1} \rightarrow A_V = \frac{a_2/b_s + b_2/b_s}{a_1/b_s + b_1/b_s} = \frac{S_{21} + S_{21}\Gamma_L}{1-(S_{22}\Gamma_L) + S_{11}(1-S_{22}\Gamma_L) + S_{21}\Gamma_L S_{12}}$$

## Transducer Power Gain

The Transducer power gain is defined as the power delivered to a load divided by the power available from a source.

$$G_T = \frac{P_{det}}{P_{av}} = \frac{|b_s|^2(1-|\Gamma_s|^2)}{|b_s|^2/(1-|\Gamma_s|^2)}$$

$$P_{det} = P_{inc} - P_{refl} = |a|^2 - |b|^2$$

$$\frac{b_2}{b_s} = \frac{S_{21}[1]}{1-(S_{11}\Gamma_s + S_{22}\Gamma_L + S_{21}\Gamma_L S_{12}\Gamma_s) + S_{11}\Gamma_s S_{22}\Gamma_L}$$

$$G_T = \frac{|S_{21}|^2(1-|\Gamma_s|^2)(1-|\Gamma_L|^2)}{|(1-S_{11}\Gamma_s)(1-S_{22}\Gamma_L) - S_{21}\Gamma_L S_{12}\Gamma_s|^2} \xrightarrow{S_{12} \approx 0} G_{TU} = |S_{21}|^2 \frac{(1-|\Gamma_s|^2)}{(1-S_{11}\Gamma_s)^2} \frac{(1-|\Gamma_L|^2)}{(1-S_{22}\Gamma_L)^2}$$

## 8 Appendix

### 8.1 Designing Components

#### Spiral Coil:

$$L = \frac{n^2 r^2}{9r+10l} [\mu H] \rightarrow L = \frac{n^2 r}{29} [H], \text{ if } l = 2r, \text{ for higher Q}$$

#### Wire Inductance:

$$L = \frac{\mu_0 \mu_r}{2\pi} \ln \frac{b}{a} [\mu H] \rightarrow \text{set } \frac{b}{a} = 50 = \text{distant ground plane}$$

#### Plate Capacitor:

$$C = \frac{\epsilon_0 \epsilon_r A}{d} [F]$$

### 8.2 Slotted T-line

- A known load e.g. Short is connected:

$$a) \Gamma = \frac{Z_L - Z_0}{Z_L + Z_0} = -1, \text{ here: } Z_L = 0$$

$$b) SWR = \frac{1+|\Gamma|}{1-|\Gamma|} = \infty$$

c) Distance between 2 minima =  $\frac{\lambda}{2}$

- The unknown load is connected:

$$a) SWR = \frac{1+|\Gamma|}{1-|\Gamma|} \rightarrow |\Gamma|$$

$$b) e^{j(\theta L - 2\beta l)} = -1; l = l_{min short} - l_{min load} > 0$$

$$c) \Gamma_L = |\Gamma| e^{j\theta L}$$

$$d) Z_L = Z_0 \left( \frac{1+\Gamma_L}{1-\Gamma_L} \right)$$

You can also solve from 2.a) with the help of the smith chart: just move "1" towards load.

### 8.3 Critical Length for Digital Interconnects

$$l_c = \frac{t_r \cdot v}{2}, t_r = \text{rise time}, v = \text{wave speed}$$

also used:  $l_c = \frac{t_r \cdot v}{1.5}$

### 8.4 Transmission matrix

The T-matrices are multiplied in the same way as the ABCD parameters when networks are cascaded.

$$\begin{pmatrix} b_1 \\ a_1 \end{pmatrix} = \begin{pmatrix} T_{11} & T_{12} \\ T_{21} & T_{22} \end{pmatrix} \cdot \begin{pmatrix} a_2 \\ b_2 \end{pmatrix}$$

$$\begin{pmatrix} T_{11} & T_{12} \\ T_{21} & T_{22} \end{pmatrix} = \begin{pmatrix} \frac{S_{12}S_{21} - S_{11}S_{22}}{S_{21}} & \frac{S_{11}}{S_{21}} \\ \frac{-S_{22}}{S_{21}} & \frac{1}{S_{21}} \end{pmatrix}$$

reciprocal:  $S_{12} = S_{21} \rightarrow T_{11}T_{22} - T_{12}T_{21} = 1$